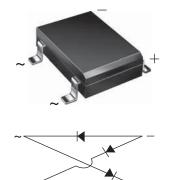
EDF1AS, EDF1BS, EDF1CS, EDF1DS

Vishay General Semiconductor

Miniature Glass Passivated Ultrafast Surface Mount Bridge Rectifiers



www.vishay.com

Case Style DFS

PRIMARY CHARACTERISTICS					
Package	DFS				
I _{F(AV)}	1 A				
V _{RRM}	50 V, 100 V, 150 V, 200 V				
I _{FSM}	50 A				
I _R	5 µA				
V_F at I_F = 1.0 A	1.05 V				
t _{rr}	50 ns				
T _J max.	150 °C				
Diode variations	Quad				

FEATURES

- UL recognition, file number E54214
- Ideal for automated placement
- Ultrafast reverse recovery time for high frequency
- High surge current capability



- Meets MSL level 1, per J-STD-020, LF maximum COMPLIANT peak of 260 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

MECHANICAL DATA

Case: DFS

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked on body

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	EDF1AS	EDF1BS	EDF1CS	EDF1DS	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	V
Maximum RMS voltage	V _{RMS}	35	70	106	140	V
Maximum DC blocking voltage	V _{DC}	50	100	150	200	V
Maximum average forward output rectified current at T_A = 40 °C ⁽¹⁾	I _{F(AV)}	1.0			А	
Peak forward surge current single half sine-wave superimposed on rated load	I _{FSM}	50			А	
Rating for fusing (t < 8.3 ms)	l ² t	10		A ² s		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150			°C	

Note

⁽¹⁾ Pulse test: 300 ms pulse width, 1 % duty cycle

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	EDF1AS	EDF1BS	EDF1CS	EDF1DS	UNIT
Maximum instantaneous forward voltage drop per diode	1.0 A ⁽¹⁾	V _F	1.05				V
Maximum DC reverse current at rated	T _A = 25 °C	1-	5.0				μA
DC blocking voltage per diode	T _A = 125 °C	IR		mA			
Maximum reverse recovery time per diode	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$	t _{rr}	50			ns	

Note

⁽¹⁾ Pulse test: 300 ms pulse width, 1 % duty cycle

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THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER SYMBOL EDF1AS EDF1BS EDF1CS EDF1DS		EDF1DS	UNIT				
Typical thermal resistance ⁽¹⁾	$R_{ ext{ heta}JA}$		°C/W				
Typical mermanesistance (*)	$R_{ ext{ heta}JL}$	12				0/10	

Note

⁽¹⁾ PCB mounted with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

ORDERING INFORMATION (Example)							
PREFERRED P/N	RED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE BASE QUAN		BASE QUANTITY	DELIVERY MODE			
EDF1DS-E3/45	0.406	45	50	Tube			
EDF1DS-E3/77	0.406	77	1500	13" diameter paper tape and reel			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

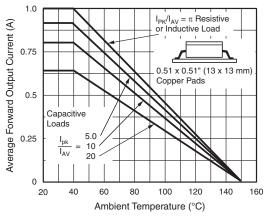


Fig. 1 - Derating Curves Output Rectified Current

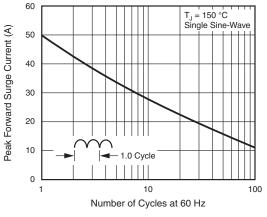


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

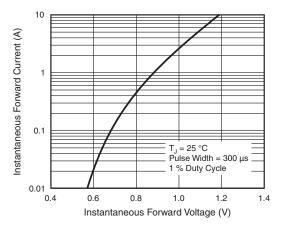


Fig. 3 - Typical Forward Characteristics Per Diode

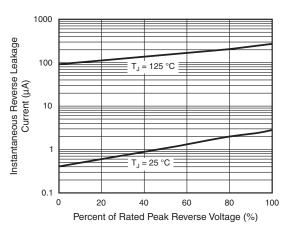


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

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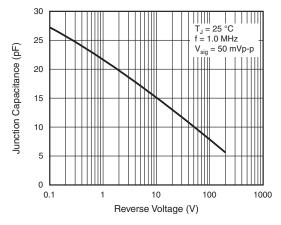
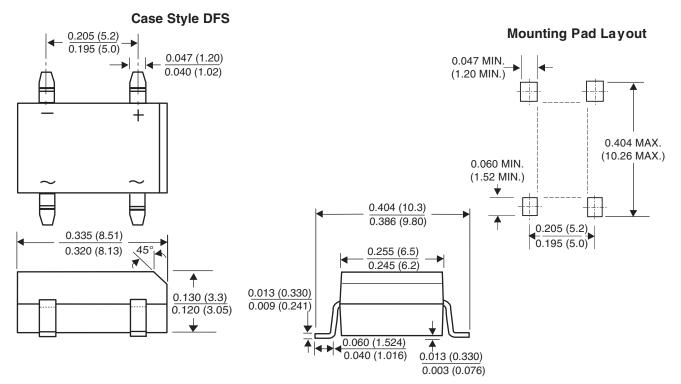


Fig. 5 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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